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Push-Pull Configuration of High Power MOSFETs for Generation of Nanosecond Pulses for Electroporation of Cells

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Abstract — A power MOSFET-based push-pull configuration nanosecond-pulse generator has been designed, constructed, and characterized to permeabilize cells for biological and medical applications. The generator can deliver pulses with durations ranging from 80ns up to 1 μ s and pulse amplitudes up to 1.4kV. The unit has been tested for *in-vitro* experiments on a medulloblastoma cell line.

Following the exposure of cells to 100ns, 200ns and 300ns electric field pulses, permeabilization tests were carried out, and viability tests were conducted to verify the performance of the generator. The maximum temperature rise of the biological load was also calculated based on Joule heating energy conservation and experimental validation.

Our results indicate that the developed device has good capabilities to achieve well controlled electro-manipulation *in-vitro*.

Keywords: *Medical and Biological Effects, Circuit Design and Applications, EM Field Theory and Numerical Techniques, Passive Components and Circuits, Si-based Devices and IC Technologies*

I. INTRODUCTION AND BACKGROUND

Classical electroporation implies the application of controlled pulsed direct current / electric field in the milli-to-micro second (ms – μ s) regime to cells and tissues. The applied electric field pulses are known to result in increased plasma membrane permeabilization thus enabling the introduction of small molecules and modulation of cell viability [1-6]. Using suitable protocols, electroporation has been successfully exploited as a medical ablation technique intraoperatively, laparoscopically and percutaneously [1-6].

Nanosecond electroporation (using high-voltage pulses with a width of a few nanoseconds up to a few hundred nanoseconds) is a further development of the classical electroporation. Literature suggests it has additional potentials for cell manipulation and control of cell physiology [3]. Nanosecond-pulse effects include: calcium (Ca^{++}) release, ion channels activation and apoptosis induction [3, 7-10].

Ablation of cancer tissue using nanosecond pulsed electric fields has been demonstrated. In some cases this technique resulted in complete tumour remission [11-17]. Furthermore, this treatment strategy stimulates the immune system thus determining an immunogenic cell death. The activation of the immune system prevented tumour regrowth when a second cancer cell injection was conducted in xenograft *in-vivo* models [12-15].

Nanosecond pulsed electric field could be additionally interesting for the treatment of cancer stem cells (CSCs) [18]. Primary cancers, such as Medulloblastoma (MB), are extremely challenging to treat with conventional therapies (i.e. chemotherapy and radiotherapy) and this has been linked to the presence of CSCs [1, 19-21]. Unlike normal cancer cells, CSCs possess stem-cell like properties and the ability to recover from cytotoxicity, leading to tumour initiation, invasion and relapse [1, 22-23].

In 2014, approximately 11,000 people were diagnosed with primary brain tumour in the UK with a median survival rate of 15 months and a 5-year survival rate of ~4 % [19-20]. Therefore, there is a crucial need for an alternative therapeutic treatment to eradicate or selectively neutralise CSCs, which may well require the development of a compact low-cost nanosecond pulsed electric field generator.

Advancement of semiconductor technology, particularly Silicon Carbide (SiC) has made possible to develop a cost-effective (<£350) compact (99mm x 254mm x 244mm) nanosecond pulsed electric field generator which utilizes off-the-shelf components to match the performance once achieved by much bulkier and more expensive technologies [24-30]. In this paper, a new generator is presented (Section II) and its realization described together with experimental characterization (Section III). *In-vitro* investigation of MB cell line permeabilization and viability were carried out to test the performance of the new generator in operational conditions (Section III). Specifically, a D283 MB cell line rich in MB CSCs in a 50 Ω buffer solution [31] was treated using an electric

field amplitude of 1 MV/m, and pulse widths extending from 100ns to 300ns.

II. MATERIALS AND METHODS

Micro-millisecond pulse generators capable of producing electric field strengths up to 100kV/mm are available commercially [24-26]. In comparison to micro-millisecond pulse generators, there are significantly fewer high-voltage nanosecond pulsed electric field generators available commercially [27-30]. In recent years there have been numerous developments of nanosecond high-voltage pulsed electric field generators within the research field, with over 500 citations since 2017 on Google Scholar [32].

Traditionally, coaxial transmission line-based implementations, such as Blumlein, in correlation with spark-gap, Marx bank or diode opening switch techniques have been used to generate high-voltage nanosecond-pulses [33-36]. These techniques can produce pulses with very high amplitude (voltages in excess of 5kV), short durations (widths varying from 1ns to 300ns), with fast rise time (< 2 ns). Yet there is complexity associated with these designs.

In recent years the use of power modules, such as Metal Oxide Semiconductor Field Effect Transistors (MOSFETs), Insulated-Gate Bipolar Transistors (IGBTs) and Bipolar Junction Transistors (BJTs) has been demonstrated in literature as a method to produce high-voltage nanosecond-pulses in various pulse generator designs. Designs include: MOSFET or IGBT stacking (series, parallel or crowbar design), solid state Marx bank, capacitor array methodology etc or a combination of these methodologies [33-38]. Table 1 summarises the advantages and disadvantages of the various technologies in producing nanosecond electric pulses.

The requirement for these developed nanosecond electric pulse generators is to produce pulses with duration of 100ns to 300ns with amplitudes in excess of 1kV, into a 50 Ω load, whilst being cost-effective. From Table 1, it is concluded that utilizing MOSFETs, IGBTs or BJTs is the practical choice to deliver the nanosecond-pulse generator requirement.

With the latest advancements in semiconductor and SiC material technology, recent power components can deliver voltage pulses in excess of 1.7kV with pulse widths in the sub-microsecond regime. Comparing commercially available MOSFETs, IGBTs and BJTs, MOSFET technology is the most suited semiconductor technology for this nanosecond electric pulse generator design. MOSFETs unlike IGBTs and BJTs are cheaper and can produce pulses within the 100ns to 300ns regime with transition times (rise and fall time) faster than 100ns, although all three have breakdown voltages (collector-emitter or drain-source voltage) in excess of 1kV. The comparison between MOSFET, IGBT and BJT is summarized in Table 2 when comparing a typical commercial component available on the market (uk.rs-online.com).

Table 1. Summary of the comparative performance between the various techniques for producing nanosecond electric pulses.

Technique	Advantages	Disadvantages
Capacitor discharge	Simple and inexpensive	Poor flexibility and control of parameters Slow capacitive discharge fall time
Transmission line	High-voltage and current pulse Possible variable duration and polarity of pulse	Complex switching element Impedance matching required Pulse width inflexibility (limited to transmission line)
Spark-gap	High-voltages and current pulse. Fast repetition frequency and pulse width	Complex switching and low control of pulse parameters eg. pulse width and amplitude
Semiconductors (MOSFETs, IGBTs and BJTs)	Simple control system Inexpensive Good control and flexibility in pulse parameters Square pulse	Low pulse amplitude (~ 2 kV _{max}) Limited rise and fall times

These features, in Table 2, make MOSFETs configured in a push-pull configuration an attractive option for the design of a compact and cost-efficient nanosecond pulsed electric field generator that meets the design requirement. Implementing the other techniques of producing nanosecond electric pulses, highlighted in Table 1 and 2, would be significantly less cost effective and efficient with the additional complexity in their design.

Table 2. Comparing MOSFET, IGBT and BJT typical parameters with existing product.

Technology	MOSFET	IGBT	BJT
Component	C2M1000170D	GT40WR21	TSC8502D
Datasheet	[39]	[40]	[41]
Breakdown voltage	1700 V	1800 V	1050
Rise time	10.5 ns	400 ns	1 μ s
Fall time	60 ns	150 ns	1.2 μ s
Cost per Unit	£4.07	£4.56	£0.153

In the following work, our modular design is presented along with its numerical and experimental characterization. The biological results obtained using the generator indicate that this compact, cost-efficient approach has a strong potential for clinical application.

A. Nanosecond-pulse generator modular design

The modular design is based on a push-pull switch configuration of two Wolfspeed's C2M1000170D SiC MOSFET (S1 and S2 in Figure 1) [39], that are directly driven by Toshiba's TLP352 photocoupler (DR1 and DR2 in Figure 1a) [42]. The ability of the design to generate the required pulses is dependent upon the switching times and maximum drain-source voltage of the MOSFETs. The SiC MOSFETs are voltage-controlled semiconductor devices that efficiently store charge in their minority carrier region resulting in very rapid turn on (t_r) and turn-off (t_f) times.

For this application it was important to choose a power MOSFET with a maximum drain-source voltage $> 1\text{ kV}$ and total switching times below 100 ns (the actual values are: $t_r = 10.5\text{ ns}$ and $t_f = 60\text{ ns}$ [39]) to generate an electrical pulse of 100 ns duration with amplitudes in excess of 1 kV, into a 50Ω load. An n-channel enhancement type MOSFET device was used, where a positive gate-source voltage (V_{gs}) opens up the channel to control the drain current (i_D). The transconductance characteristic (i_D as a function of V_{gs}) was also considered carefully when choosing the most appropriate MOSFET to use.

Selecting a push-pull configuration of MOSFETs over the conventional transmission line-based design or other alternatives for generating nanoseconds electric pulses provides numerous advantages (Table 1 and 2). In addition for being a compact and cost-effective, this design provides a more controllable method of delivering various nanosecond electric pulses, such as: pulse widths, repetition frequency, number of pulses and pulse amplitude, in comparison to other techniques mentioned. These aspects of using power MOSFETs are advantageous for the usage of a well-controlled electro-manipulation technique while supporting further nanosecond-pulse-based applications and research in biology, medicine and/or biotechnology.

An input capacitance (C_{input}) of around 200 pF exists between the gate and the channel [42-45]. This capacitance must be charged when the device is turned on and discharged when it is turned off. The charge and discharge times must be as short as possible. A gate driver is therefore necessary to provide enough current to charge this capacitance for the necessary V_{gs} to appear across the gate-source terminals, to enable the required i_D flow. The total gate capacitance (C_{gate}) is made up of the gate-source capacitance (C_{gs}) and the gate-drain capacitance (C_{gd}) as the current required to charge up this capacitance (i_c) is given:

$$C_{gate} = C_{input} = (C_{gs} + C_{gd}(1 + g_m R_L)) \quad (1)$$

$$i_c = C_{gate} \frac{dV_{gs}}{dt} \quad (2)$$

where g_m is the transconductance ($\frac{di_D}{dV_{gs}}$) of the MOSFET and R_L is the load impedance. In this work R_L is 50Ω , representing

the standard commercial impedance of cables and connectors necessary to link the generator to the biological load.

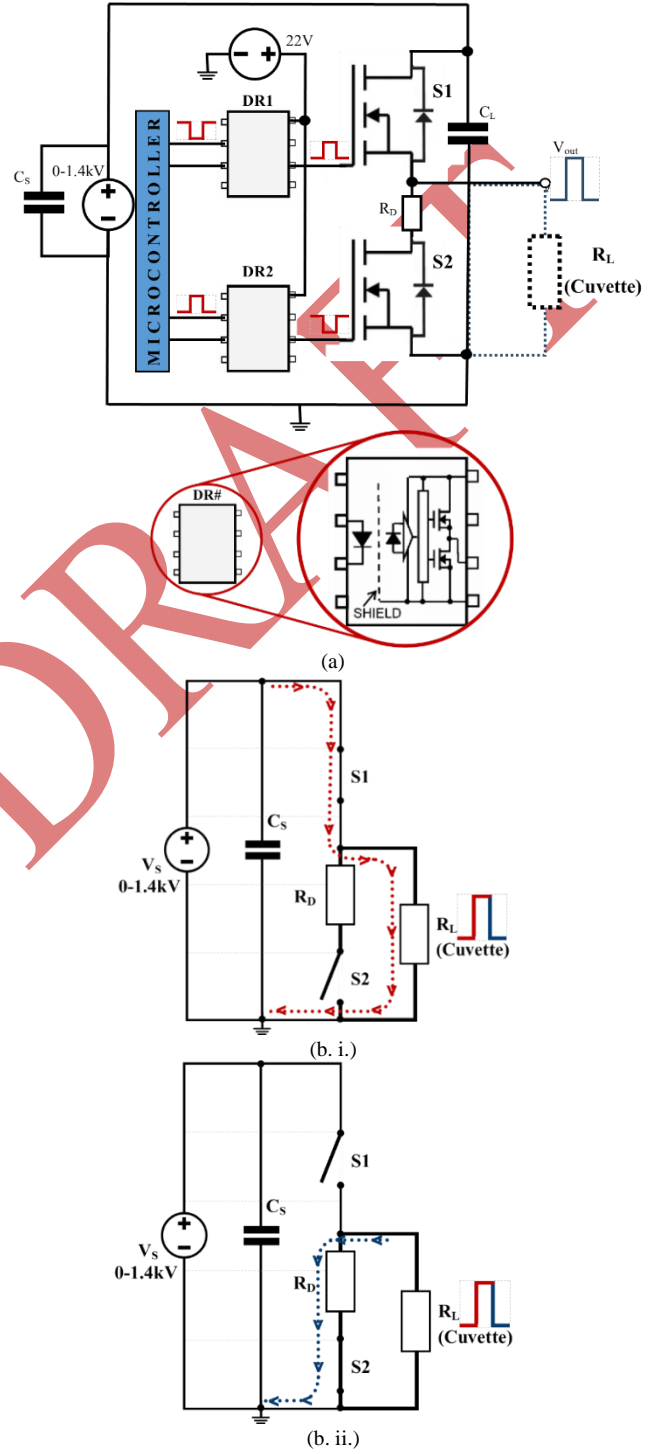


Figure 1. The basic modular design of the developed nanosecond generator (a) simplified schematic. Note: DR1 and DR2 circuits have been simplified for graphical clarity. (b) simplified equivalent circuit of the generator showing the current path when: i. S1 is closed and S2 open; ii. S1 is open and S2 is closed.

The selected opto-couplers (DR1 and DR2) operate as a gate driver, which provides the necessary current ($2.5A_{max}$) to charge and discharge the C_{gs} and C_{gd} [43-45].

The power MOSFET was chosen based on the fastest possible switching times, which in turn are determined by the charging and discharging times of C_{gs} and C_{gd} (mentioned above).

If a single MOSFET is used to generate the sub-microsecond high-voltage pulses at a load, then the gate-source capacitance of the MOSFET has to be charged and discharged resulting in unacceptably long switching times. This is particularly true for the discharge of the input capacitance necessary to switch the pulse off. The fall-time of the pulse is dictated by the discharge time constant of the gate-source capacitance of the MOSFET and is dependent on the gate-source capacitance and load resistance ($t_f = \tau = C_{gs} R_L$).

To overcome this problem two MOSFETs can be used in a push-pull configuration, as shown in Figure 1a. This switching topology means that when the high-side MOSFET (S1) is open ('off') the low-side MOSFET (S2) is closed ('on'), and vice versa. The relationship between the two-gate driver signals to the MOSFET switches is synchronized and complementary to one another.

The simplified equivalent circuit of the nanosecond generator is illustrated in Figure 1b.i and ii. When S1 (the high-side MOSFET) is turned on, a high-voltage is applied to the load. The current flow (red dotted line), for this action, is shown in Figure 1b.i. In addition, applying high-voltage to the load, S1 determines the pulse duration (width) and rise time at the load.

When S1 is turned off, S2 is turned on. This creates a second path for the current to flow (blue dotted line), Figure 1b.ii. The switching of S2 creates a low impedance path, which allows the high-voltage pulse delivered at the load to discharge to ground. Thus, S2 controls the pulse fall time at the load.

The R_D resistor in Figure 1 and 3 protects the circuit from a failure / open control signal, ensuring a pull-down of the gate signal of the high-side MOSFET (S1), turning S1 off, and that the pulse seen at the load is grounded (0V) and not floating ($> 0V$). R_3 and R_5 , in Figure 3, provide similar modality to R_D , but they ensure pull-down of the gate driving signals to S1 and S2 from there respected photocoupler (DR1 and DR2).

Implementing a push-pull configuration results in a faster fall-time than is possible for a single MOSFET implementation and leads to a square shaped, symmetrical pulsed electric field at the load, Figure 2.

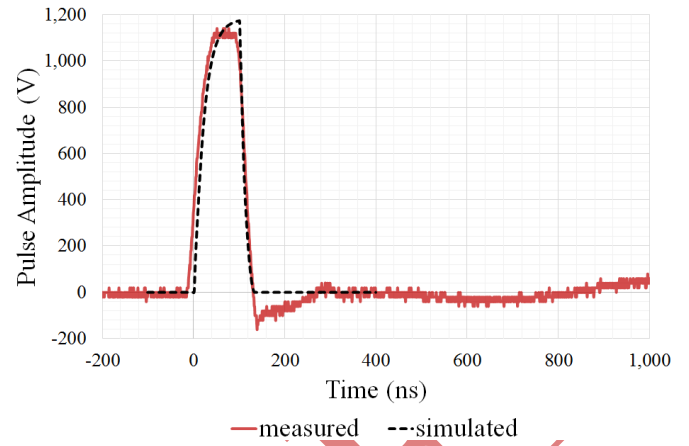


Figure 2. 100ns pulse obtained by LTSpice simulation (black dashed line) and measured from the developed generator (red solid curve) with a 50Ω load.

It is imperative that both S1 and S2 are not switched 'on' simultaneously. In such an event, no pulse would be measured across the load as the voltage from the power supply would be grounded through a direct low impedance path to ground. This circumstance could result in shorting of the power supply and a potential temperature rise or breakdown of MOSFETs due to the high-voltage swing (1.4kV) in a low-impedance pattern.

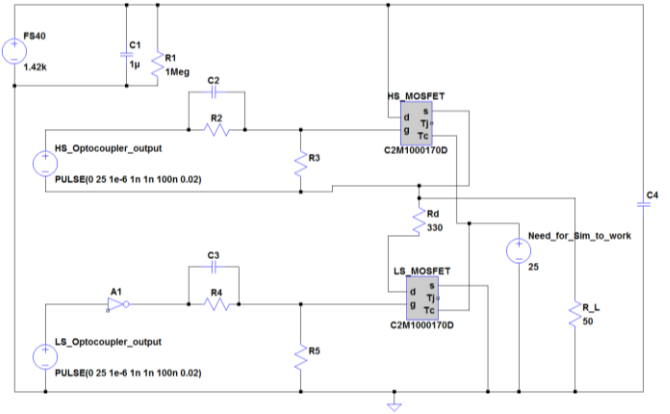


Figure 3. LTSpice simulation circuit diagram, with spice model of Wolfspeed's MOSFETs [43].

B. Simulated vs measured performances

Following the development of the nanosecond pulsed electric field generator, a LTSpice model of the modular design was developed as shown in Figure 3. The simulated design utilised the PSpice model of the C2M1000170D SiC MOSFET obtained from Wolfspeed's website [46].

Figure 4a demonstrates that the actual generator performance exceeds LTSpice simulation. It can be seen that the measured pulse across a 50Ω resistive load, in practice, is more symmetrical and has a faster risetime than the simulated pulse. This could be the result of a higher gate current in practice, thus, resulting in faster charging of the internal gate capacitance.

Figure 4.bi and 4.bii show good agreement with (1) and (2) analytical description of the MOSFET switching and driving process.

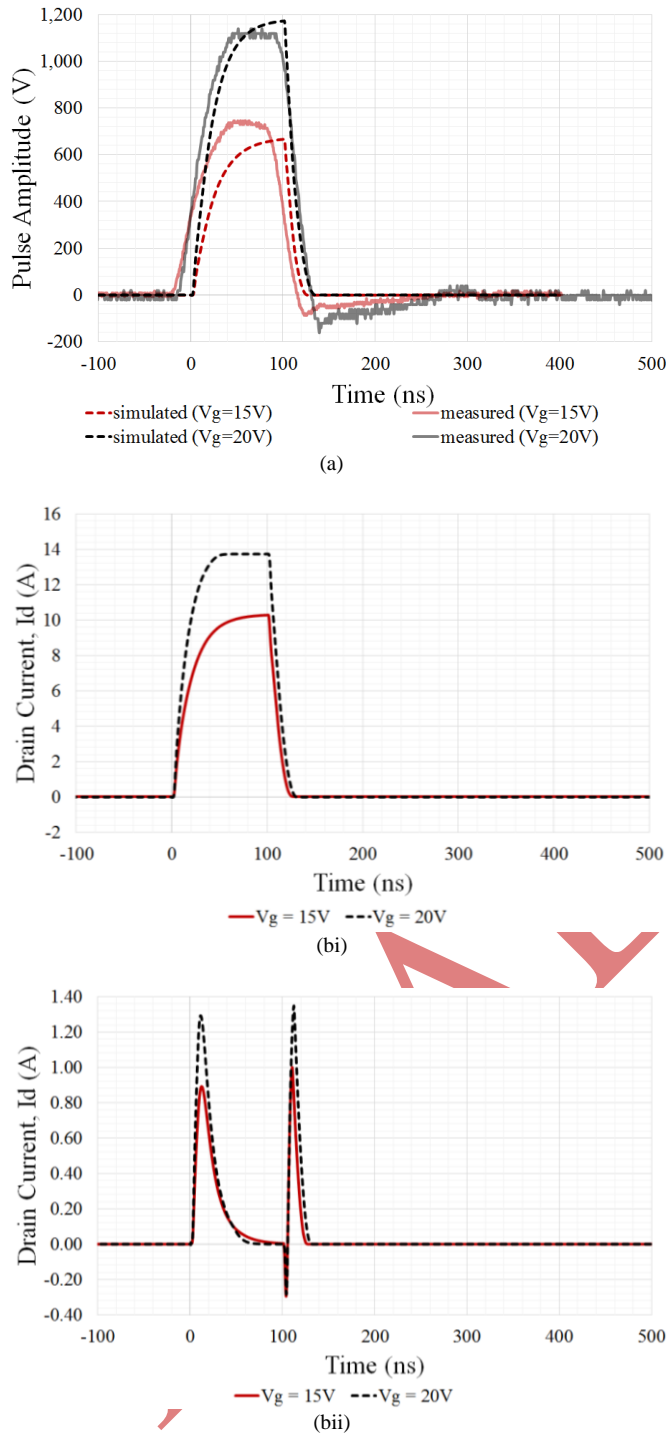


Figure 4 (a) Measured (solid lines) vs LTSpice simulation results (dashed lines) for 100 ns pulse on a 50Ω load, with various gate voltages (15V (red) and 20V (black)). (b) drain current during switching on the (i) high-side MOSFET and (ii) low-side MOSFET in LTSpice simulation with 15V (solid red line) and 20V (black dashed line) gate voltages.

Table 3 shows the bill of material for the key components used in the generator. The overall cost for the bill of material for the generator was less than £350. The majority of the cost is the enclosure and the high-voltage supply (FS40).

Table 3. Bill of material of the generator’s critical components (at time of write-up).

Component	Distributor	Cost per Unit (£)	Quantity
C2M1000170D SiC N-Channel MOSFET	RS Components	4.07	2
Toshiba, TLP352 Opto-coupler	RS Components	0.98	2
LT1713 Comparator	RS Components	3.93	3
XPPower FS40 High-voltage Converter	RS Components	130.04	1
Enclosure (99 mm x 254 mm x 244 mm)	Farnell	99.77	1

The high-voltage supply (FS40) is an essential component and was limited to producing a voltage output of 1.4kV. The source was capped to 1.4kV to ensure the voltage supplied to the MOSFET drain pin does not exceed its maximum drain-source breakdown voltage ($V_{DSmax} = 1.7kV$). The FS40 is a compact (57.15mm x 28.5mm x 12.7mm) proportional DC to high-voltage DC source which provides isolation from the high-voltage (0V - 1.4kV) output from its low voltage input (0V - 5V) [47].

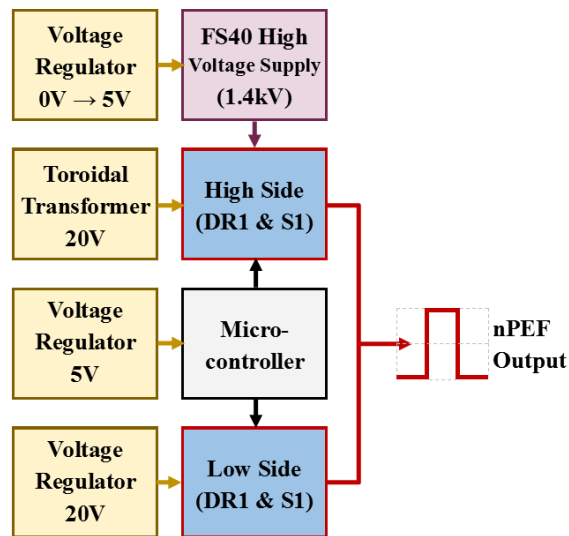


Figure 5. Design block diagram of Veroboard modules.

The generator dimensions is limited to the enclosure size (99mm x 254mm x 244mm). In future adaptations the nanosecond electric pulse generator can be smaller in size. Within the current enclosure there are unoccupied areas. Presently, the circuits are built on Veroboard, with each

subsection module of the design occupying a single board, as illustrated in Figure 5. Integrating the individual Veroboard subsections onto a single printed circuit board would significantly reduce the area occupation of the current enclosure, reducing the generator's size and cost in future implementations.

C. Nanosecond pulse verification and validation.

A Verification and Validation (V&V) process was undertaken to check if the system meets the electrical specifications outlined and also to evaluate the intended purpose of biological cells nanoporation.

The electrical specifications outlined was to generate pulsed electric fields with a pulse duration from 100ns to 300ns with voltage amplitudes in excess of 1kV, with a repetition frequency ranging from 1Hz to 50Hz, on a 50Ω load.

Table 4. Generator characteristics.

Parameters	Range	Comment
Frequency (Hz)	1 - 50	Pulse repetition frequency
Pulse Width (ns)	80 - 1000	Increments of 10ns (between 80ns-400ns) and 20ns (between 400ns-1us)
Burst	1 - continuous	Number of pulses generated successively
Pulse Amplitude (V)	250 - 1400	Can be varied by rotary potentiometer dial on the generators front panel

An ‘Arduino Uno’ microprocessor with a LCD keypad shield provides an user friendly user interface in addition to providing precise control and a wide range of pulse profiles to be generated (see Table 4). In further implementations the Arduino could be replaced by a single microcontroller chip.

Figure 6a indicates that the pulse amplitude is unaffected throughout its operating repetition frequencies of 1Hz to 50Hz (result obtained with a 50Ω resistor load and a pulse width of 100ns). Furthermore, Figure 6b also suggests that the generators performance is optimized to the intended specifications as amplitudes in excess of 1kV are generated in the pulse width range from 100ns to 300ns (result obtained with a 50Ω resistor load and 50Hz repetition frequency).

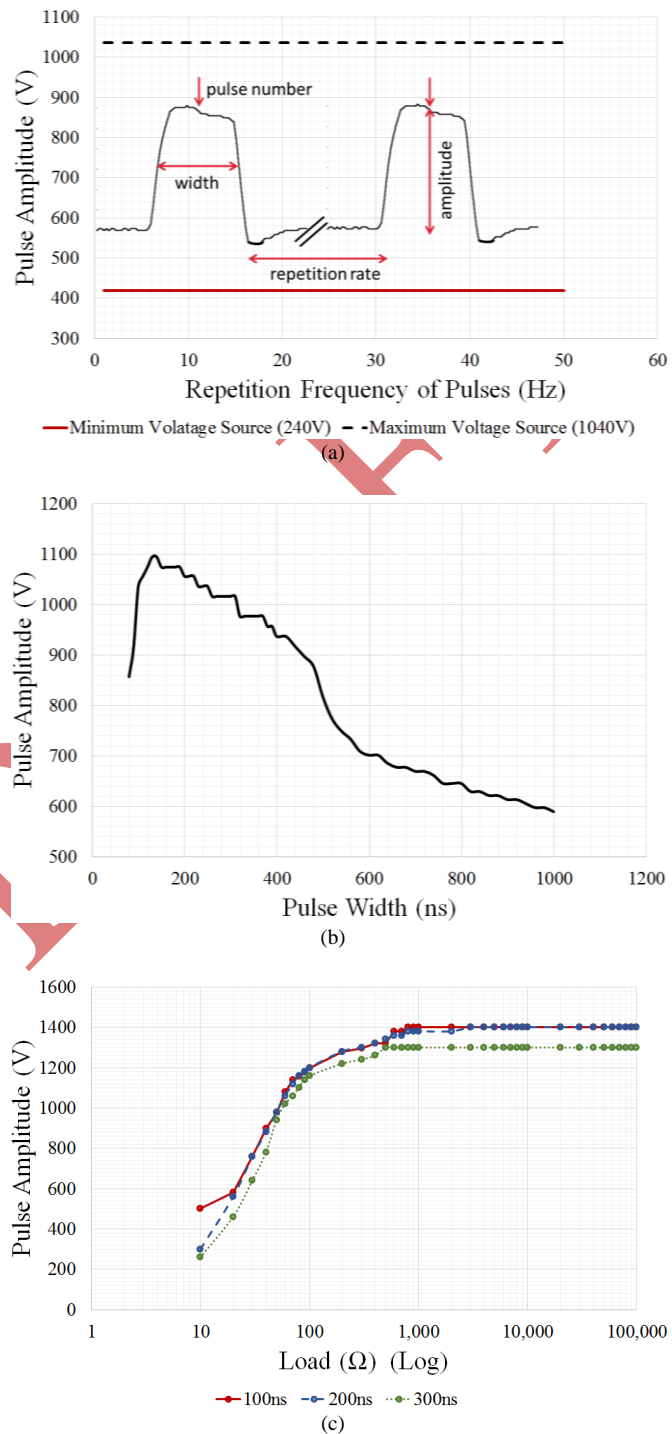


Figure 6. Measured characteristics of the generator pulse amplitude: (a) as a function of the repetition frequency 1Hz to 50Hz (with pulse widths of 100ns). (b) as a function of pulse width (at 50Hz repetition frequency). (c) as a function of load resistance for three different pulse widths (100ns, 200ns and 300ns).

On the other hand, Figure 6c indicates that the nanosecond pulsed electric field generator is impedance sensitive. With a load below 500Ω, the pulse amplitude decreases. This decrease appears linear (on a log scale) with a load equal or less than 100Ω. This effect is due to the voltage source. Like most voltage sources they are mismatched to a low impedance or

short-circuited load. Additionally, Figure 6c suggests that the power source used has an internal impedance of $\sim 30\Omega$ as a load of $\sim 30\Omega$ experiences half (700V) of the voltage generated (1400V), behaving as a voltage divider.

The load curve was obtained by loading the generator with various resistive loads of low inductance (planar resistor) and measuring the pulse amplitude observed with the particular load. Reasoning for a 50Ω load is explained in the next section, II D.

D. Biological 50Ω load

Due to the fast rise and fall times of the pulses, it was necessary to consider transmission line with a characteristic impedance of 50Ω . Cables and connector were therefore used for the cuvette housing unit that have a characteristic impedance of 50Ω . Therefore, it was necessary to match the biological load (R_L) to 50Ω . In practice, D283 cell-line suspended in standard culture medium known as Modified Eagle Medium (MEM) has an estimated impedance of $\sim 10\Omega$ due to the high conductivity of the suspending medium of around $1.5S/m$ [2, 48]. Impedance mismatch minimization between the generator, cuvette holder and the load (cuvette filled with cell solution) is imperative to guarantee the generator can deliver nanosecond electric pulses in excess of $1kV$ amplitude.

To get 50Ω impedance matching within the whole *in-vitro* set-up, when the generator is connected to a biological load, the cells were suspended in an artificial buffer solution that is able to mimic a pure resistive 50Ω load. Additionally, a 50Ω load is advantageous to minimise mismatch with other microwave and electronics, such as: components, connections and devices (e.g. oscilloscopes, voltage and current probes, attenuators, dividers).

100mL of our artificial buffer solution consists of 20mL of phosphate buffer saline (PBS), 80mL of distilled water and 8.2g of sucrose to counteract osmotic pressures of the cells because of the distilled water. The artificial 50Ω buffer solution has a conductivity of $0.3S/m$ [49].

E. In-vitro investigation set-up

High field exposure of D283 MB cell line to high 100ns to 300ns pulses were conducted by a Bio-rads commercially available 0.1cm gap, 100 μ L EP cuvettes ($1mm \times 55mm^2$) [50]. The cuvette housing unit in Figure 7a was designed by ENEA and provides a direct and easy (standard 50Ω connector) connection between the cuvette and the pulse generator (Figure 7b and c).

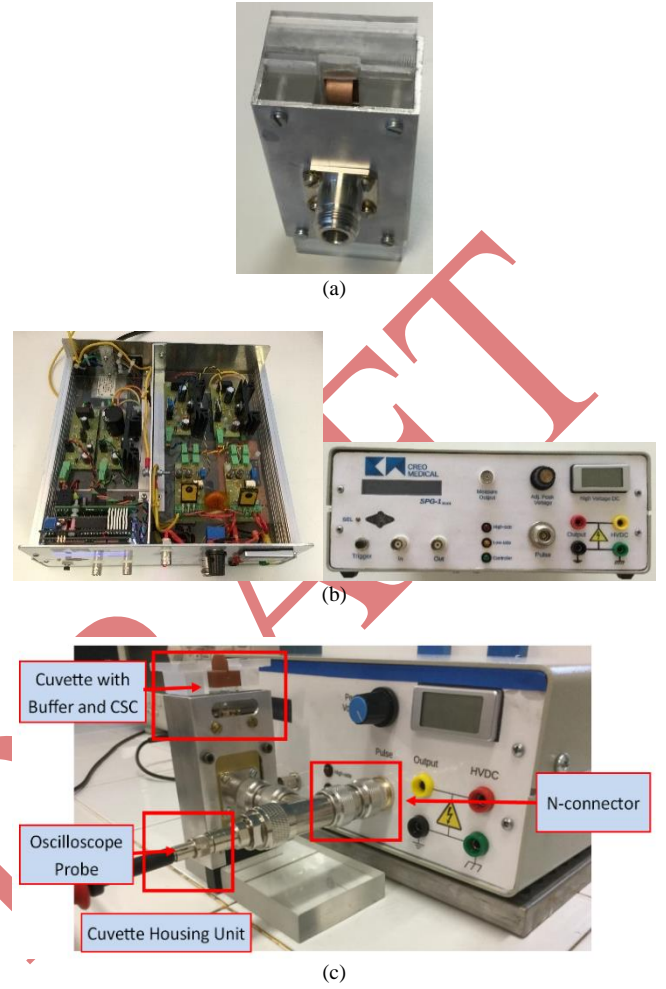


Figure 7 The *in-vitro* investigation set-up (a) ENEA's cuvette housing unit. (b) the nanosecond-pulse electric field generator (c) the global arrangement of the initial bench study to investigate the performance of the nanosecond-pulse generator on D283 MB cell line.

Furthermore, the cuvette housing units allows real-time monitoring of the applied voltage pulse via an oscilloscope to assess electric field delivered to cells. The electric field between the cuvette electrodes (that form a capacitance loaded by biological solution) has a very homogenous distribution as already suggested in [2, 51] by numerical simulations, and it can be well estimated as the ratio between the applied voltage over the electrode distance.

The complete setup for preliminary study of the D283 cell line is shown in Figure 7c. The results of permeabilization and viability tests are discussed in the next section.

III. RESULT AND ANALYSIS

A. Nanosecond-pulses delivered to the D283 cell line

The first *in-vitro* experiments aimed at characterizing the generator in terms of the real pulse waveform delivered to D283 cells, rather than to a 50Ω resistor (Figs. 2, 4 and 5).

Experiments were performed using the electroporation cuvettes filled with buffer solution containing cells (D283 cell line is mixed population of differentiated and stem like cells as reported in [49]). The voltage pulse/pulsed waveforms were captured in real time via a Tektronix TDS5054B-NV Oscilloscope [52] and a high-voltage probe (LeCory PPE 5kV [53]).

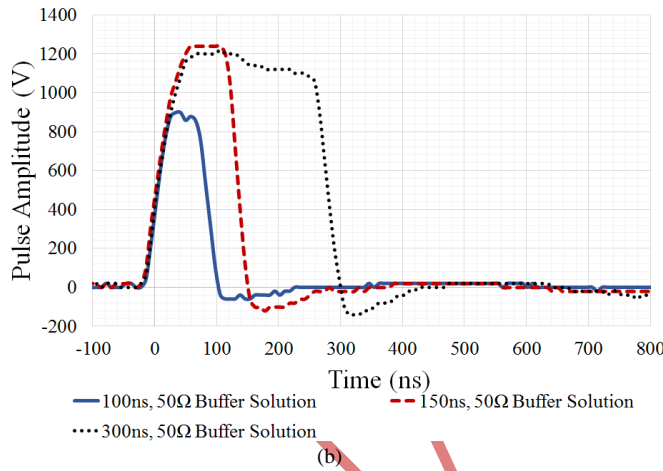
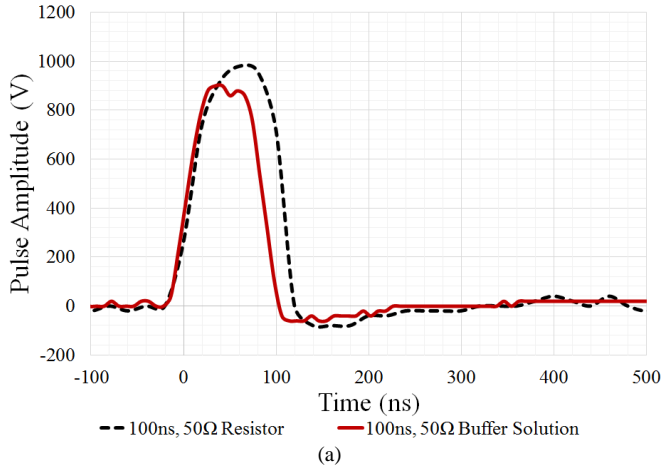


Figure 8. Measured nanosecond pulsed electric fields applied to various loads. (a) comparison of a single 100ns, 50Hz, 20 pulses with a 50Ω resistor load (black dashed line) and 50 Ω buffer solution with D283 cell line load (solid red line). (b) comparison of a single 100ns, 50Hz, 20 pulses of various widths: 100ns (blue solid line), 150ns (red dashed line) and 300ns (black dotted line) pulse, with a 50Ω buffer solution with D283 cell line load.

Figure 8a suggests that the buffer load is 50Ω, because the measured waveform of the applied 100ns pulsed electric field with the artificial buffer solution (red solid line) is comparable to the waveform measured with a 50Ω resistor (black dashed line) as a load. It can be seen that the presence of the D283 cells did not affect the electrical properties of the buffer solution medium since cells represent an extremely small fraction of the global solution volume contained within the cuvette. Therefore, the artificial 50Ω buffer solution can effectively represent a 50Ω load from an electrical point of view.

Figure 8b depicts the 100ns (blue solid line), 150ns (red dashed line) and 300ns (black dotted line) voltage pulse waveforms measured across the electroporation cuvette containing D283 MB cell line suspended with the 50Ω, 0.3S/m buffer solution. These waveforms illustrate the electrical signal delivered to the cells during the biological investigations (permeabilization and viability tests). The cells were exposed to a symmetrical voltage pulse with a maximum amplitude of $\sim 1.2\text{MV/m}$, which are similar to the results obtained in simulations, as shown in Figure 4a.

The waveforms in Figure 8b demonstrates that the 100ns, 150ns and 300ns pulses applied to the D283 MB cell line are square and symmetrical, with minimal overshoot and ringing.

B. Permeabilization tests

For the permeabilization tests D283 cells were grown in a humidified atmosphere at 3 °C and 5% CO₂ in MEM supplemented with 10% fetal bovine serum and 1 % of penicillin streptomycin. Cells were scraped, centrifuged and suspended in the artificial 50Ω buffer, and then YO-PRO-1 (3μM) was added 5 minutes before the electric pulses delivery.

To test cell permeabilization, pulses were delivered according to the protocol as reported in Table 5. A non-pulsed sample was also included in the analysis.

Table 5. Cell population permeabilization rate following electric field exposure.

Pulse Width (ns)	E-field Strength (MV/m)	Number of Pulses	Repetition Frequency (Hz)	Permeabilization Rate (%)
100	~ 0.9	1	1	5
100	~ 0.9	20	1	5
200	~ 1.2	1	1	5
200	~ 1.2	20	1	75
300	~ 1.2	1	1	18
300	~ 1.2	20	1	90
0	0	0	0	5

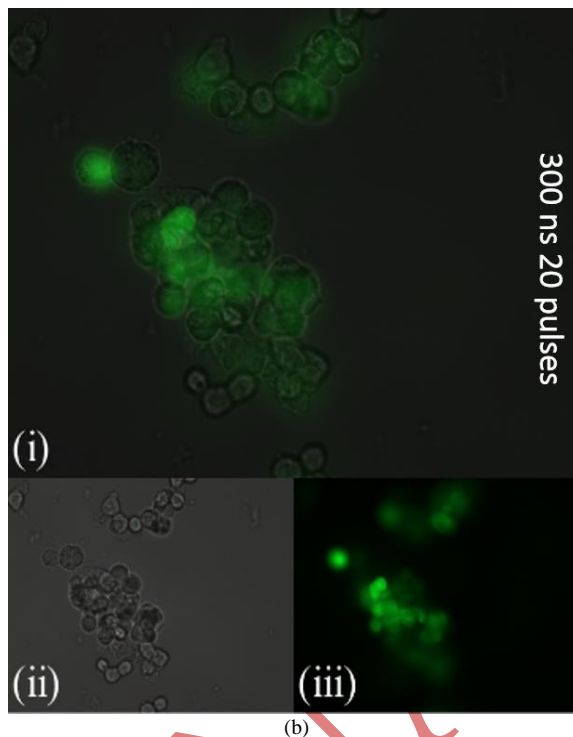
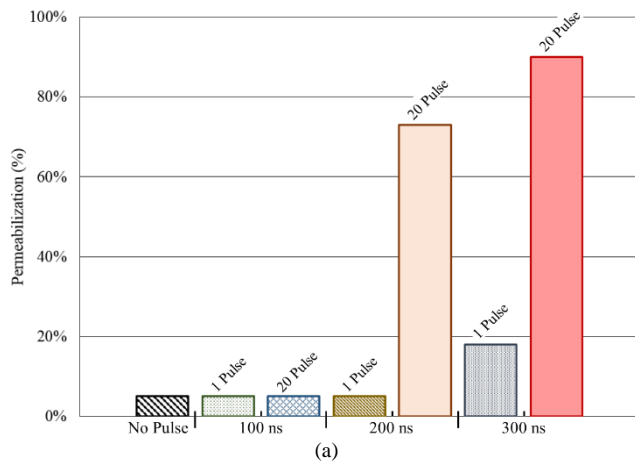


Figure 9 (a) D283 permeabilization rate following exposure to electric pulses with various pulse parameters. (b) YO-PRO-1 uptake after exposure to 20 pulses of 300ns at 1.2MV/m: i. bright field superimposed to fluorescence microscope image. ii. bright field images. iii. fluorescence microscope image.

Figure 9a illustrates various permeabilization rates of the D283 cells exposed with different pulse protocols in terms of pulse width, and number of pulses. The same figure indicates that exposing D283 cells to 200ns and 300ns signals with 20 consecutive pulses resulted in more than 70% and 90% of permeabilized cells respectively. This is further confirmed by observing Figure 9b where images of permeabilized D283 are shown. For the same sample, the bright field image is also presented (Figure 9bii) to demonstrate the presence of D283 cells in the reviewed sample.

Electropermeabilized cells were observed under fluorescence microscopy (YO-PRO-1 wavelength emission = 510nm), and percent of permeabilization is computed as the ratio of fluorescent cells over the total imaged D283 cells, in three different observation areas.

C. Viability test

To assess cell viability, the well-established trypan blue exclusion test was performed. D283 cells were scraped and suspended in the artificial 50Ω buffer. Then the cells were electropermeabilized using the pulses protocol in Table 5.

Viability was evaluated immediately after the pulse delivery and at 24 and 48 hours after the electric treatment. Specifically, 10μL of trypan blue was added to the 10μL of cell solution. Live cells were automatically counted using a commercial system (Luna II by Logos) in disposable counting chambers.

In Figure 10 viability is expressed as the percentage ratio of the pulsed sample over the control (non-pulsed sample). These data show a high cell viability when 100ns and 200ns are applied. When 300ns pulses are delivered to cells, viability of cells is reduced especially when 20 consecutive pulses of 300ns are applied (see viability after 24 and 48 hours from exposure).

Bright field images after 48 hours from the exposure are reported in Figure 10. These images confirm that D283 cells exposed to 100ns and 200ns are slightly affected by electric pulses compared to the non-pulsed (sham) sample. Cell viability and morphology seemed much more degraded when 20 pulses of 300ns durations are delivered.

These observations lead to the hypothesis that D283 start to be irreversibly permeabilized when multiple pulses (20) of 300ns are applied. Fewer pulses (less than 20) seem to act on D283 cell line in a reversible manner.

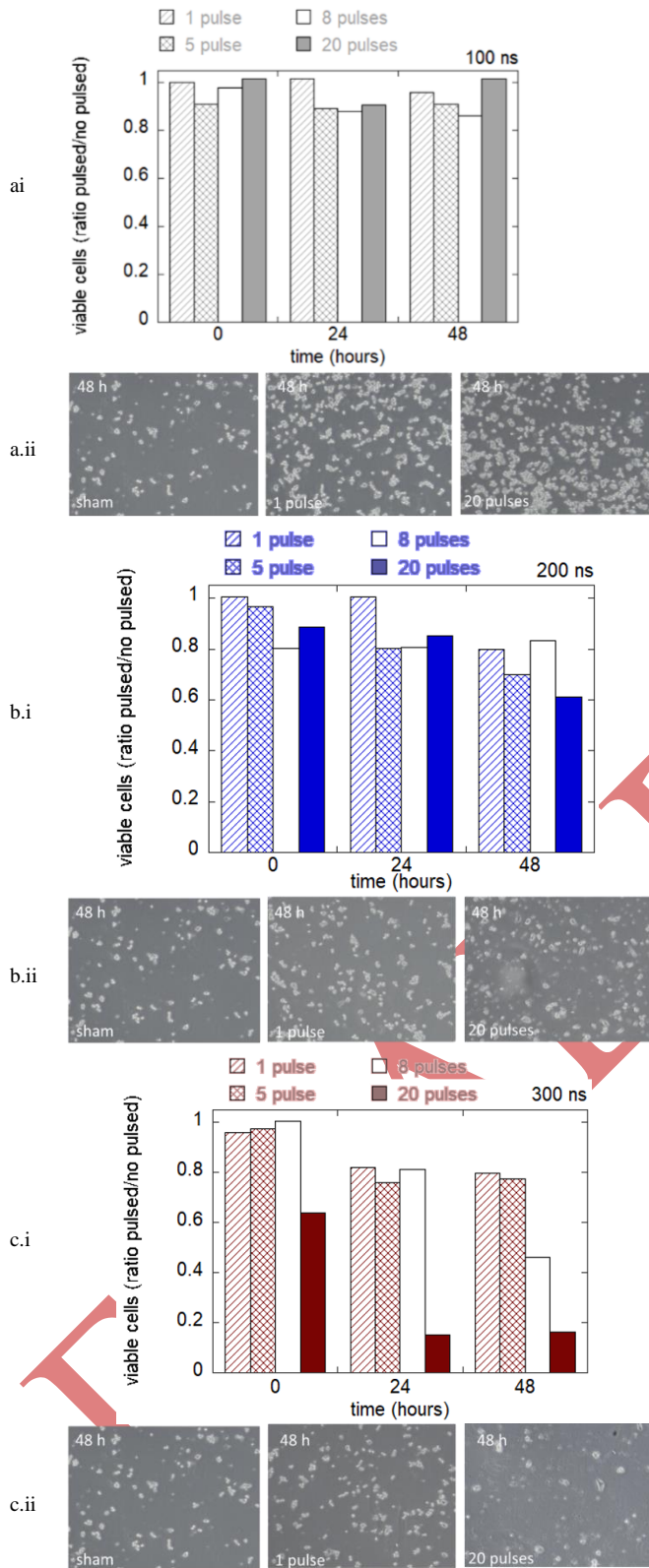


Figure 10 (i) Result of viability test in panel (ii) bright field images after 48 hours from the electric field exposure of width: (a) 100ns (b) 200ns (c) 300ns.

D. Non-thermal effect

The short duration (nanoseconds) and low repetition frequency (1Hz) of the electric pulses ensure that the energy delivered into the biological system should be nonthermal [54-55]. A non-thermal approach of neutralising CSCs is an appealing treatment approach since it could allow for a targeted neutralization of a tumour without heating the cells above body temperature. This would result in predominantly sparing healthy cells, extracellular matrix, nearby vessels and structures while allowing tissue regrowth and preventing unwanted damage to patient brain tissue [1, 54-55].

To verify that the delivered electric protocols resulted in a non-thermal effect, as literature suggests [1, 50-51], a cuvette heating analysis using specific heat capacity equation has been conducted.

The estimated temperature rise per pulse, ΔT (3), and the maximum mean rate of temperature rise, ΔT_{max} (4) where calculated using the applied nanosecond pulsed electric field parameters (pulse width, pulse amplitude, number of pulses) and biological load parameters.

$$\Delta T = \frac{E}{c m} = \frac{\left(\frac{V^2}{Z} P_w\right)}{c (\rho vol)} \quad (3)$$

$$\Delta T_{max} = \frac{E}{c m} N = \frac{\left(\frac{V^2}{Z} P_w\right)}{c (\rho vol)} N \quad (4)$$

In equations (3) and (4), E is the heated energy (Joules, J) due to the applied nanosecond pulsed electric field parameters. E, depends on V, the applied pulse amplitude (Volts), Z is the impedance of the biological load (Ω), P_w is the pulse width/duration of the applied electric pulse (seconds, s). c is the specific heat capacity (J/Kg $^{\circ}$ C) and m is the mass (Kg) of the biological load. m is determined by the density, ρ (kg/m³), and the total volume, vol (m³) of the biological load. In equation (4), N is the number of pulses delivered to the buffer solution.

The biological load consists of an impedance of 50 Ω (as shown) and a specific heat capacity of 4.18J/g $^{\circ}$ C, the same heat coefficient value as water, because the buffer solution consists mainly of water. In addition to having the same specific heat capacity as water, the buffer solution also has the same density as water (~1000kg/m³). The total volume of liquid (buffer solution/biological load) the cuvette can occupy is 55x10⁻⁹m³ (as the dimension of the cuvette is 1mm x 5mm x 11mm).

As the D283 cell line consists of a small fraction of the global solution volume it can be assumed that the heating effect on the cell solution is the same as the heating effect on the simple buffer solution.

Table 6 shows the estimated temperature rise per pulse and the maximum mean rate of temperature rise the 50 Ω buffer solution experienced with various pulse parameters (amplitude, pulse width and frequency).

Table 6. Heating effect of applied nanosecond pulsed electric field on the buffer solution.

Pulse Width (ns)	Pulse Amplitude (V)	Number of pulses (N)	ΔT (mK or $^{\circ}\text{C}$ per pulse)	ΔT_{max} (K/s or $^{\circ}\text{C/s}$)
100	900	1	7.04	0.007
100	900	20	7.04	0.141
200	1200	1	25.02	0.025
200	1200	20	25.02	0.500
300	1200	1	37.53	0.038
300	1200	20	37.53	0.751

This theoretical thermal investigation clearly indicates that the change in the temperature of the biological load is dependent on the pulse properties. Properties such as: pulse width, pulse amplitude, and repetition frequency (maximum mean rate of temperature rise). Our computation highlights that the short duration and low repetition frequency of electric field pulses delivers non-thermal energy into the buffer solution and therefore the D283 cells [1, 54-55]. Table 6 indicates that the maximum temperature rise the cells experience within the cuvette is 37.53mK or $^{\circ}\text{C}$, with a potential of rising by 1.876mK or $^{\circ}\text{C}$ in a second, assuming that no heat is dissipated away from the surrounding environment (air, material, equipment etc).

The cuvette is designed to have an impedance of 50 Ω in order to absorb all of the incident power. The voltage across the load is 900V peak for a duration of 100ns. This has a peak power of 16.2kW, which only depends on the voltage and the impedance. If 16.2kW is delivered to the cuvette for 100ns then this is equivalent to 2mJ of energy. The volume of fluid in the cuvette is 55ml. The 1.6mJ energy delivery will increase the temperature of 55ml of water by 7.0mK.

Assuming that the pulse heats only the fluid, and not the walls of the cuvette, the heat will escape from the fluid in the cuvette through the walls. The surface area of the walls is 142mm². Perspex has a thermal conductivity of 0.21W/m/K. A temperature gradient of 0.07K/mm would carry away all the heat from one pulse through the walls in a second. If the thickness of the walls is 5mm then there would be about a third of a degree Kelvin across the walls.

None of the fluid in the cuvette is more than 0.5mm from a wall, so heat transfer from the centre of the fluid to the walls should be at least as quick as through the cuvette walls and should not result in a large temperature rise.

The temperature in the centre of the fluid in the cuvette is unlikely to rise more than one degree Kelvin, and this depends to a large extent on the heat transfer from the cuvette to its surroundings, which is affected by such things as the material of the holding brackets, the contact area and pressure, and the amount of movement in the surrounding air.

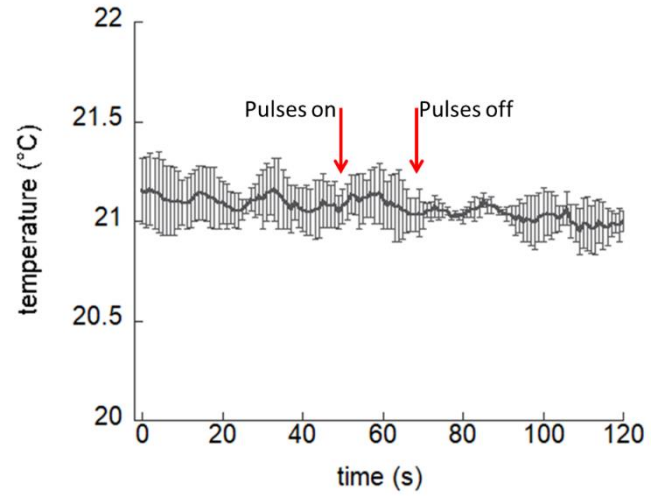


Figure 11. Temperature trend within the electroporation cuvette electrodes before and after the electric pulses delivery. Bars represent standard deviation of the measurements over three independent acquisitions.

To further demonstrate absence of thermal effects, the temperature of the buffer contained in the electroporation cuvette was measured using a fiber optic probe (LumaSense OEM Modules, optic fiber dimensions 0.3mm) directly placed between the electrodes before (1min), during and after (1min) the exposure. The strongest exposure condition employed in bio-experiments (300ns, 20 pulses at 1Hz) was considered for this test. No macroscopic temperature increase is observed, as shown in Figure 11. Therefore, due to the very small temperature rise computed numerically, which is even macroscopically not detectable at experimental level, multiphysics numerical simulations to accurately determine the temperature rise of the fluid in the cuvette were forfeited.

IV. CONCLUSION

A nanosecond electric field pulse generator has been designed and fully characterized from a pulse amplitude, pulse duration and repetition rate into a range of load impedances. It has also been characterised in terms of its biological efficacy.

The designed generator has proven to be a very useful instrument for biologist to carry out a range experiments on cells. The ability to vary the pulse width, repetition frequency, number of pulses and amplitude is a key feature for such application. This versatile generator is attractive to biologists, since it supports a wide range of pulse protocols to define optimal electric parameters for cell neutralization. Additionally, due to the use of conventional and non-specialist components

this generator is a very cost-effective solution in comparison to pulsed electric field generators that are currently commercially available.

The generator is well matched to the applicators (cuvette with 50Ω buffer solution and cuvette holder); delivering square (flat-top) electric field pulses with minimal ringing and overshoot.

The overall system including the generator, the cuvette housing unit, and buffer solution resulted in successful permeabilization of D283 cells. More than 70% of cell population were deemed to be permeabilized when multiple pulses (20) of 200ns or longer pulse width were delivered. A viability study, following permeabilization tests, seems to indicate that D283 starts to be irreversibly permeabilized when multiple pulses (20) of 300ns are delivered. The achieved cell permeabilization is non-thermal even for the stronger exposure condition.

Further perspectives of our work imply technological improvements, as the possibility to deliver different shaped pulse waveforms (e.g. bipolar), as well as introducing an impedance matching network to improve matching strategy between the generator output and the load (cell line, tissue etc). A matching strategy is imperative in future work for a more efficient electric-field distribution of ~1.4MV/m at all load impedances. In reality, this aspect is significant for *in-vivo* and clinical application as biological matter, such as cell-line and tissue etc, are naturally of low impedances, ~10Ω.

The use of smaller dyes, with respect to YO-PRO-1, for detection of cell electroporation is a consideration for future work. Indeed, one interesting possibility is the transport of small ions as Ca, through the uptake of specific markers as Fluo4 [56]. Recent study suggested verification of eventual microthermal heating at cell level, looking at the fluorescence of the Rhodamine B dye [54].

The vision is for the designed nanosecond pulsed electric field generator to achieve targeted non-thermal neutralization of MB CSCs supporting both *in-vitro* and *in-vivo* test, while supporting further nanosecond-pulse-based applications in biology, medicine and/or biotechnology in a cost-effective manner.

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From 1997 to 2002, he was a Senior Microwave Engineer with Gyrus Medical Ltd. In 2003, he founded MicroOncology Ltd. (now Creo Medical Limited), Chepstow, U.K., to develop his ideas based on dynamic impedance-matching techniques and integrated RADAR measurement techniques using Ku-band energy for the treatment of breast tumors. In 2009, he was given a personal Chair with the Medical Microwave Systems Research Group, Bangor University. He is also the Chief Technical Officer (CTO) and founder of Creo Medical Limited.